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### 1N957B, -1 thru 1N992B, -1, e3 DO-35

Silicon 500 mW Zener Diodes

#### DESCRIPTION

The popular 1N957B thru 1N992B series of 0.5 watt Zener Voltage Regulators provides a selection from 6.8 to 200 volts in standard 5% or 10% tolerances as well as tighter tolerances identified by different suffix letters on the part number. These glass axial-leaded DO-35 Zeners are also optionally available with an internal-metallurgical-bond option by adding a "-1" suffix as well as RoHS Compliant by adding an "e3" suffix. Microsemi also offers numerous other Zener products to meet higher and lower power applications.

APPEARANCE



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IMPORTANT: For the most current data, consult *MICROSEMI's* website: <u>http://www.microsemi.com</u>

#### FEATURES

- JEDEC registered 1N957B(-1) to 1N992B(-1) series
- Internal metallurgical bond option available by adding a "-1" suffix (similar to military product)
- Surface Mount equivalents available as MLL957B to MLL992B or with "-1" suffix for bonded in the DO-213AA MELF style package (consult factory for others)
- RoHS Compliant devices available by adding "e3" suffix
- DO-7 glass body axial-leaded Zener equivalents are also available

MAXIMUM RATINGS

Operating and Storage temperature: -65°C to +175°C

• Thermal Resistance: 250 °C/W junction to lead at 3/8

(10 mm) lead length from body, or 310<sup>°</sup>C/W junction to ambient when mounted on FR4 PC board (1 oz Cu)

with 4 mm<sup>2</sup> copper pads and track width 1 mm, length

• Steady-State Power: 0.5 watts at  $T_L \le 50^{\circ}C$  3/8 inch

mounted on FR4 PC board as described for thermal

• Forward voltage @200 mA: 1.1 volts (maximum) for

1N957B - 1N985B and 1.3 V for 1N985 - 1N992B

(10 mm) from body or 0.48 W at  $T_A < 25^{\circ}$ C when

resistance above (also see Figure1)

Solder Temperatures: 260 °C for 10 s (max)

#### **APPLICATIONS / BENEFITS**

- Regulates voltage over a broad operating current and temperature range
- Extensive selection from 6.8 to 200 V
- Standard voltage tolerances are plus/minus 5% with B suffix, 10 % with A suffix identification
- Tight tolerances available in plus or minus 2% or 1% with C or D suffix respectively
- Flexible axial-lead mounting terminals
- Nonsensitive to ESD per MIL-STD-750 Method 1020
- Minimal capacitance (see Figure 3)
- Inherently radiation hard as described in Microsemi MicroNote 050

#### MECHANICAL AND PACKAGING

- CASE: Hermetically sealed axial-lead glass DO-35 (DO-204AH) package
- TERMINALS: Tin-Lead (Sn/Pb) or RoHS Compliant annealed matte-Tin plating solderable per MIL-STD-750, method 2026
- POLARITY: Cathode indicated by band. Diode to be operated with the banded end positive with respect to the opposite end for Zener regulation
- MARKING: Part number
- TAPE & REEL option: Standard per EIA-296 (add "TR" suffix to part number)
- WEIGHT: 0.2 grams
- See package dimensions on last page

25 mm



ELECTRICAL CHARACTERISTICS\* @25°C

Silicon 500 mW Zener Diodes

#### NOMINAL MAX. DC ZENER MAX. SURGE MAX. REVERSE ZENER MAX. ZENER IMPEDANCE ZENER VOLTAGE TEST CURRENT CURRENT LEAKAGE MAX. TEMP. JEDEC (Note 3) CURRENT COEFFICIENT CURRENT (Note 2) (Note 4) (Note 5) TYPE NUMBER ٧z **Z**<sub>ZT</sub> @ I<sub>ZT</sub> IZT @ І<u><sub>zк</u></u></sub> I<sub>ZM</sub> IZSM I<sub>R</sub> @ VR Z<sub>7k</sub> αvz VOLTS OHMS VOLTS (Note 1) OHMS mΑ mΑ mΑ mΑ μA %/°C 1N957B 18.5 300 150 +0.05 6.8 4.5 700 1.0 55 5.2 1N958B 7.5 16.5 5.5 700 .5 50 275 75 5.7 +0.058 6.2 1N959B 8.2 15.0 6.5 700 .5 45 250 50 +0.065 1N960B 7.5 .5 25 6.9 9.1 14.0 700 41 225 +0.0681N961B 10 8.5 700 25 38 200 10 12.5 7.6 +0.075 1N962B 11 11.5 9.5 700 .25 32 175 8.4 +0.076 5 1N963B .25 5 5 12 10.5 11.5 700 31 160 +0.0779.1 1N964B 13 95 700 .25 28 99 +0.07913.0 150 8.5 .25 1N965B 700 5 15 16 25 130 114 +0.0821N966B 17 .25 24 120 12.2 +0.08316 7.8 700 5 1N967B 18 7.0 21 750 .25 20 110 5 13.7 +0.0851N968B 20 6.2 25 750 .25 18 100 5 15.2 +0.086 1N969B 22 5.6 29 750 .25 16 5 16.7 +0.087 90 1N970B 24 5.2 33 750 .25 15 80 5 18.2 +0.088 1N971B 27 4.6 41 750 .25 70 5 20.6 +0.090 13 1N972B 30 4.2 49 1000 .25 12 65 5 5 22.8 +0.091 33 .25 1N973B 3.8 58 1000 60 25.1 +0.092 11 5 1N974B 36 3.4 70 1000 .25 10 55 27.4 +0.093 1N975B 39 3.2 80 1000 .25 9.5 46 5 29.7 +0.0941N976B 3.0 .25 8.8 5 43 93 1500 44 32.7 +0.09547 .25 2.7 105 40 35.8 1N977B 1500 7.9 5 +0.095.25 .25 5 1N978B 51 2.5 125 1500 7.4 37 38.8 +0.0961N979B 56 22 150 2000 68 35 5 42.6 +0.0961N980B 62 2.0 185 2000 .25 6.0 30 5 47.1 +0.097

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25

25

5.5

5.0

4.6

4.1

3.7

3.3

3.1

27

24

2.2

20

18

28

26

23

21

18

16

15

13

12

11

10

q

5

5

5

5

5

5

5 5

5

5

5

5

51.7

56.0

62.2

69.2

76.0

83.6

91 2

98.8

114.0

121.6

136.8

152.0

+0.097

+0.098

+0.098

+0.099

+0.11

+0.11

+0.11

+0.11

+0.11

+0.11

+0.11

+0.11

\* JEDEC Registered Data

68

75

82

91

100

110

120

130

150

160

180

1.8

1.7

1.5

1.4

1.3

1.1

10

0.95

0.85

0.80

0.68

0.65

230

270

330

400

500

750

900

1100

1500

1700

2200

2500

2000

2000

3000

3000

3000

4000

4500

5000

6000

6500

7100

8000

1N981B

1N982B

1N983B

1N984B

1N985B

1N986B

1N987B

1N988B

1N989B

1N990B

1N991B

NOTE 1: The JEDEC type numbers shown (B suffix) have a +/-5% tolerance on nominal Zener voltage. The suffix A is used to identify +/-10% tolerance; suffix C is used to identify +/-2%; and suffix D is used to identify +/-1% tolerance; no suffix indicates +/-20% tolerance.

NOTE 2: Zener voltage (V<sub>Z</sub>) is measured after the test current has been applied for 20 +/- 5 seconds. The device shall be suspended by its leads with the inside edge of the mounting clips between .375" and .500" from the body. Mounting clips shall be maintained at a temperature of 25 +8/-2°C.

NOTE 3: The zener impedance is derived when a 60 cycle ac current having an rms value equal to 10% of the dc zener current (I<sub>zT</sub> or I<sub>ZK</sub>) is superimposed on I<sub>zT</sub> or I<sub>ZK</sub>. Zener impedance is measured at 2 points to ensure a sharp knee on the breakdown curve and to eliminate unstable units. See MicroNote 202 for variation in dynamic impedance with different zener currents.

**NOTE 4:** The values of I<sub>ZM</sub> are calculated for a +/- 5% tolerance on nominal zener voltage. Allowance has been made for the rise in zener voltage above V<sub>ZT</sub> which results from zener impedance and the increase in junction temperature as power dissipation approaches 400 mW. In the case of individual diodes I<sub>ZM</sub> is that value of current which results in a dissipation of 400 mW at 75°C lead temperature at 3/8" from body.

NOTE 5: The surge for I<sub>ZSM</sub> is a square wave or equivalent half-sine wave pulse of 1/120 sec. duration.

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#### GRAPHS



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Page 3

1N957B - 992B, e3

(DO-35)